

Ultrafast Rectifier, 3 A FRED Pt®



SMB (DO-214AA)



FEATURES

- Ultrafast recovery time, reduced Q_{rr} and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, ultrafast recovery time, and fast recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

PRODUCT SUMMARY

Package	SMB (DO-214AA)
$I_{F(AV)}$	3 A
V_R	600 V
V_F at I_F	0.99 V
t_{rr} typ.	41 ns
T_J max.	175 °C
Diode variation	Single die

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$	$T_L = 110\text{ °C}$ (1)	3	
Non-repetitive peak surge current per leg	I_{FSM}	$T_J = 25\text{ °C}$, 6 ms square pulse	55	A
Operating junction and storage temperatures	T_J, T_{Stg}		-55 to +175	°C

Note

(1) Mounted on PCB with minimum pad size

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	V_F	$I_F = 3\text{ A}$	-	1.15	1.35	
		$I_F = 3\text{ A}, T_J = 150\text{ °C}$	-	0.99	1.2	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	-	3	μA
		$T_J = 150\text{ °C}, V_R = V_R$ rated	-	-	100	
Junction capacitance	C_T	$V_R = 600\text{ V}$	-	3.9	-	pF

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$I_F = 1.0\text{ A}$, $dI_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	41	-	ns
		$I_F = 1.0\text{ A}$, $dI_F/dt = 50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	52	-	
		$I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{rr} = 0.25\text{ A}$	-	-	65	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	38	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	52	-	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^{\circ}\text{C}$	-	5.6	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	7.3	-	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	108	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	193	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		-55	-	+175	$^{\circ}\text{C}$
Thermal resistance, junction to case	$R_{thJC}^{(1)}$		-	-	18	$^{\circ}\text{C}/\text{W}$
Thermal resistance, junction to ambient	$R_{thJA}^{(1)}$		-	-	90	
Approximate Weight			0.1			g
			0.003			oz.
Marking device		Case style SMB (DO-214AA)	3U6H			

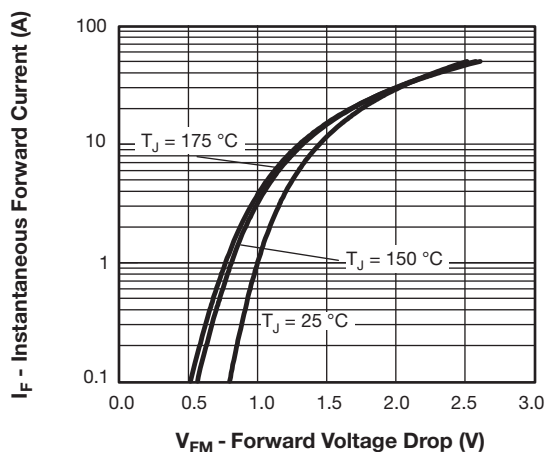
Note
⁽¹⁾ Mounted on PCB with minimum pad size


Fig. 1 - Typical Forward Voltage Drop Characteristics

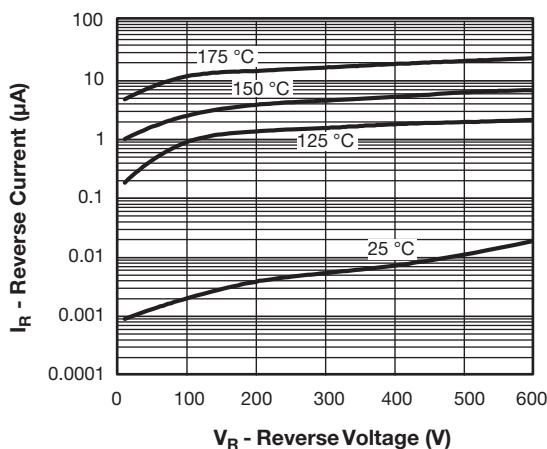


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

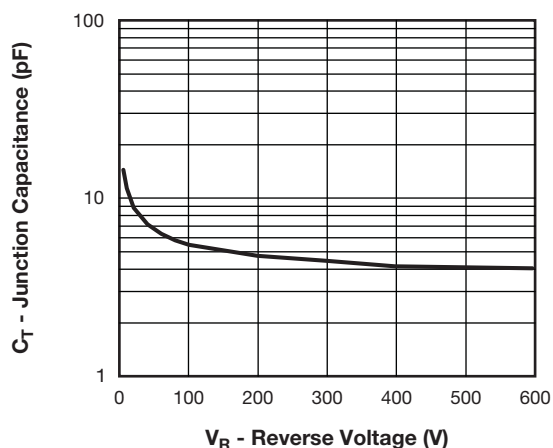


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

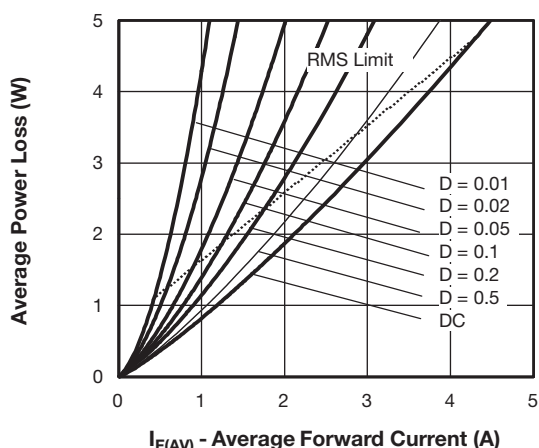


Fig. 5 - Forward Power Loss Characteristics

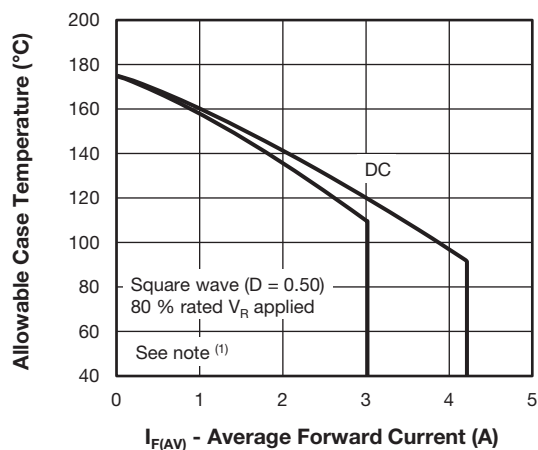
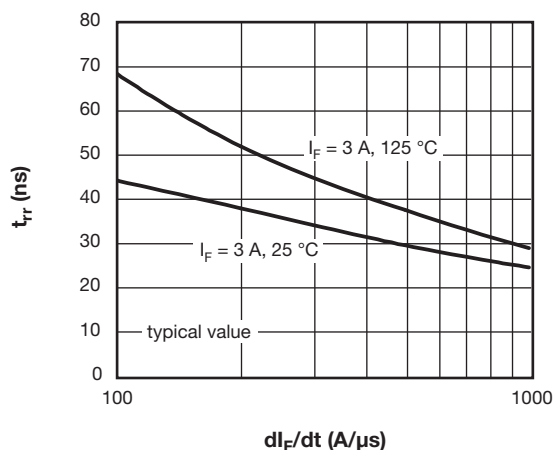
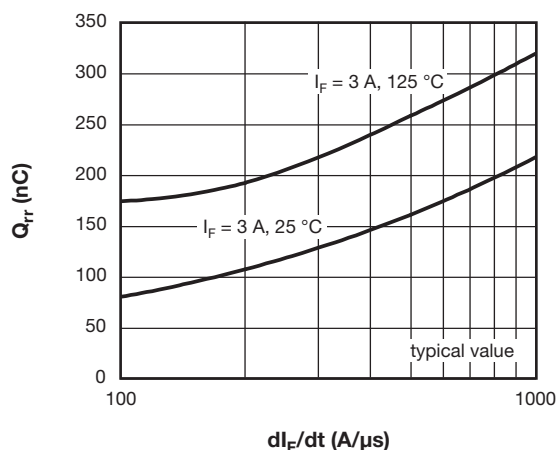


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

Fig. 7 - Typical Stored Charge vs. dI_F/dt

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 5);
 P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

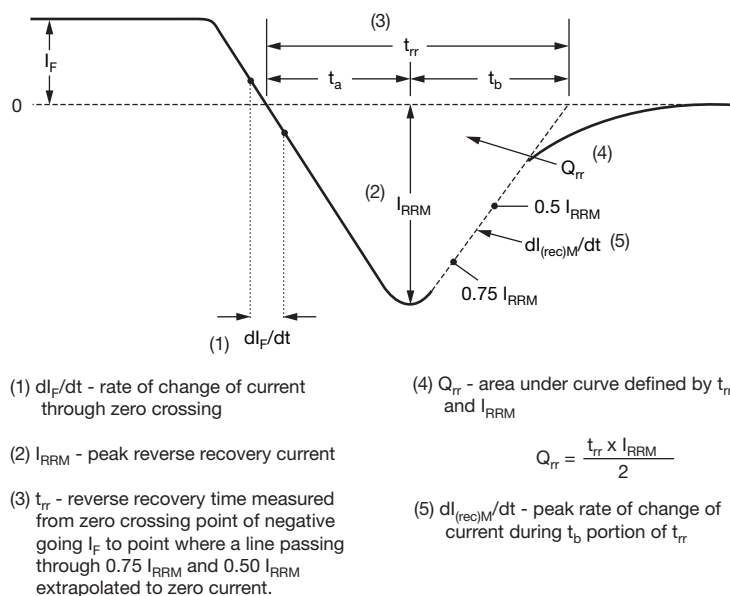


Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code	VS-	3	E	G	U	06	W	H	M3
	1	2	3	4	5	6	7	8	9

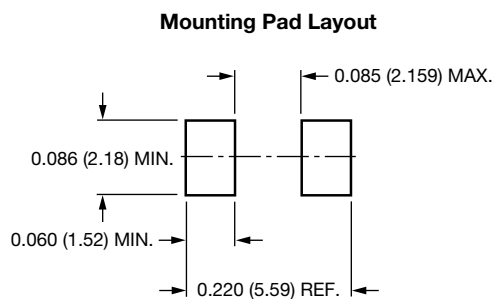
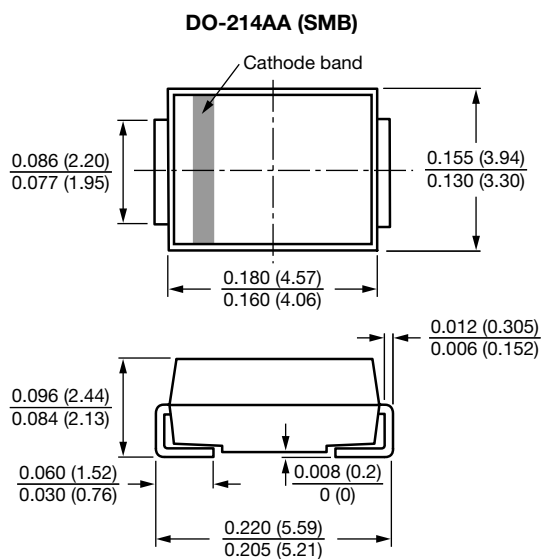
- 1** - Vishay Semiconductors product
- 2** - Current rating (3 = 3 A)
- 3** - Circuit configuration:
E = single diode
- 4** - G = SMB package
- 5** - Process type,
U = ultrafast recovery
- 6** - Voltage code (06 = 600 V)
- 7** - W = special
- 8** - H = AEC-Q101 qualified
- 9** - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-3EGU06WHM3/5BT	5BT	3200	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95401
Part marking information	www.vishay.com/doc?95624
Packaging information	www.vishay.com/doc?95404

SMB

DIMENSIONS in inches (millimeters)





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